

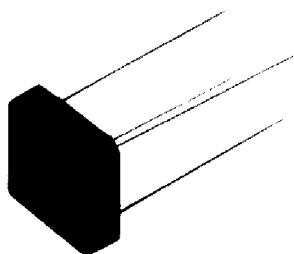
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KBPC1, KBPC6 Series

Single Phase Rectifier Bridge, 3 A, 6 A



FEATURES

- Suitable for printed circuit board or chassis mounting
- Compact construction
- High surge current capability

DESCRIPTION

The KBPC series of single phase rectifier bridge consists of four silicon junctions connected as a full bridge. These devices are intended for general use in industrial and consumer equipment.

PRODUCT SUMMARY

$I_{O(AV)}$	3.0 A, 6.0 A
V_{RRM}	50 V to 1000 V

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	KBPC1	KBPC6	UNITS
I_O		3	6	A
I_{FSM}	50 Hz	50	125	A
	60 Hz	55	137	
I^2t	50 Hz	12.5	78	A ² s
	60 Hz	11.4	71	
V_{RRM}	Range	50 to 1000		V
T_J		- 40 to 150		°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS

PART NUMBER	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	V_{RMS} , MAXIMUM RECOMMENDED RMS SUPPLY VOLTAGE V
KBPC1005 KBPC6005	50	50	20
KBPC102 KBPC602	200	200	80
KBPC104 KBPC604	400	400	125
KBPC106 KBPC606	600	600	250
KBPC108 KBPC608	800	800	380
KBPC110 KBPC610	1000	1000	500



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Quality Semi-Conductors

KBPC1, KBPC6 Series

Single Phase Rectifier
Bridge, 3 A, 6 A

FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		KBPC1	KBPC6	UNITS
Maximum DC output current	I _O	T _C = 50 °C, resistive or inductive load		3.0	6.0	A
		T _C = 50 °C, capacitive load		2.4	4.7	
Maximum peak one cycle, non-repetitive surge current	I _{FSM}	t = 10 ms, 20 ms	Following any rated load condition and with rated V _{RRM} reapplied	50	125	A
		t = 8.3 ms, 16.7 ms		55	137	
Maximum I ² t capability for fusing	I ² t	t = 10 ms	Initial T _J = T _J maximum 100 % V _{RRM} reapplied	12.5	78	A ² s
		t = 8.3 ms		11.4	71	
		t = 10 ms		17.7	110	
		t = 8.3 ms		16.1	1000	
Maximum I ² √t capability for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied		177	1105	A ² √s
Maximum peak forward voltage per diode	V _{FM}	I _{FM} = 0.5 x I _O , T _J = 25 °C		1.1	1.2	V
Typical peak reverse leakage per diode	I _{RM}	T _J = 25 °C, 100 % V _{RRM}		10	10	mA
		T _J = 150 °C, 100 % V _{RRM}		1.0	1.0	
Operating frequency range	f			40 to 1000		Hz
Maximum repetitive peak reverse voltage range	V _{RRM}			50 to 1000		V

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	KBPC1	KBPC6	UNITS
Operating and storage temperature range	T_J, T_{Stg}	- 40 to 150		$^\circ\text{C}$
Thermal resistance, junction to case	R_{thJC}	-	-	K/W
Approximate weight		5	6	g
		0.18	0.21	oz.

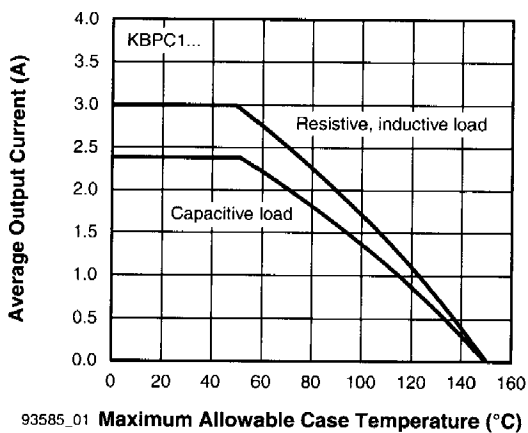


Fig. 1 - Case Temperature Ratings

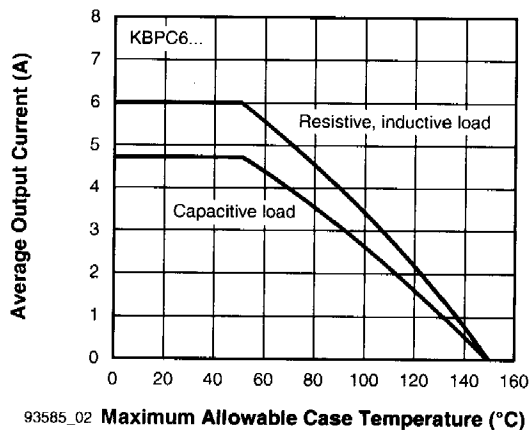


Fig. 2 - Case Temperature Ratings

D-72

DIMENSIONS in millimeters (inches)

